

PNP -1.0A -30V Middle Power Transistor

Parameter	Value
V_{CEO}	-30V
I _C	-1.0A

Features

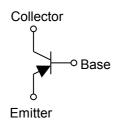
- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SCR293P
- 3) Low V_{CE(sat)}

$$V_{CE(sat)} = -0.35V(Max.)$$

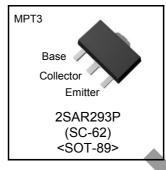
 $(I_C/I_B = -500mA/ -25mA)$

4) Lead Free/RoHS Compliant.

•Inner circuit



Outline



Applications

Motor driver , LED driver Power supply

Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SAR293P	MPT3	4540	T100	180	12	1,000	ML

● Absolute maximum ratings (Ta = 25°C)

	Unit
_30	V
-30	V
-6	V
-1.0	А
-2.0	А
0.5	W
2.0	W
150	°C
−55 to +150	°C
)	-30 -6 -1.0 -2.0 0.5 2.0 150

^{*1} Pw=10ms, single pulse

^{*2} Each terminal mounted on a reference land

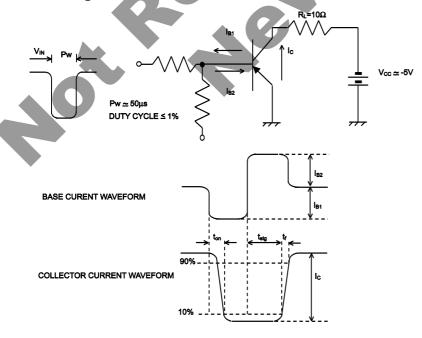
^{*3} Mounted on a ceramic board (40×40×0.7 mm)

●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-30	-	-	V
Collector-base breakdown voltage	BV _{CBO}	$I_{C} = -10 \mu A$	-30	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	I _E = -10μA	- 6	ı	-	V
Collector cut-off current	I _{CBO}	V _{CB} = -30V	ı	-	-100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = -6V	-	-	-100	nA
Collector-emitter saturation voltage	V _{CE(sat)} *1	$I_C = -500 \text{mA}, I_B = -25 \text{mA}$		-0.15	-0.35	V
DC current gain	h _{FE}	$V_{CE} = -2V, I_{C} = -100 \text{mA}$	270	-	680	-
Transition frequency	f _T	$V_{CE} = -2V$, $I_E = -100$ mA f=100MH _Z	-	320	-	MHz
Output capacitance	C _{ob}	$V_{CB} = -10V, I_{E} = 0A,$ f = 1MHz	-	7	-	pF
Turn-on time	t _{on} *2	I _C = -500mA		60	-	ns
Storage time	t _{stg} *2	I _{B1} = -25mA I _{B2} =25mA	-	160	-	ns
Fall time	t _f *2	V _{CC} ≃ –5V	-	50	-	ns

^{*1} Pulsed

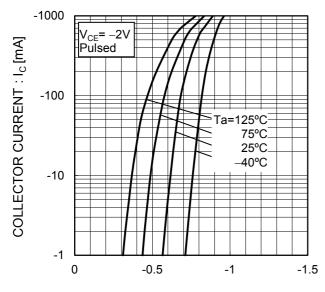
•Switching time test circuit



^{*2} See switching time test circuit

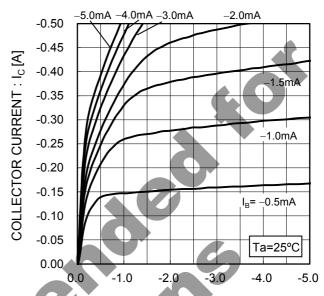
●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics



BASE TO EMITTER VOLTAGE : $V_{BE}[V]$

Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : V_{CE} [V]

Fig.3 DC Current Gain vs. Collector Current(I)

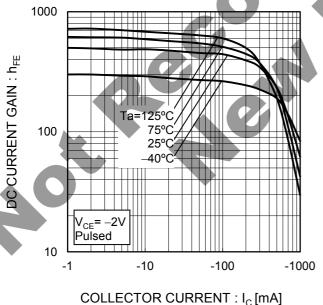
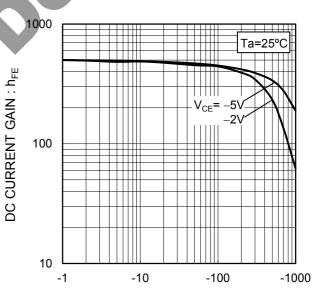


Fig.4 DC current gain vs. output current (II)

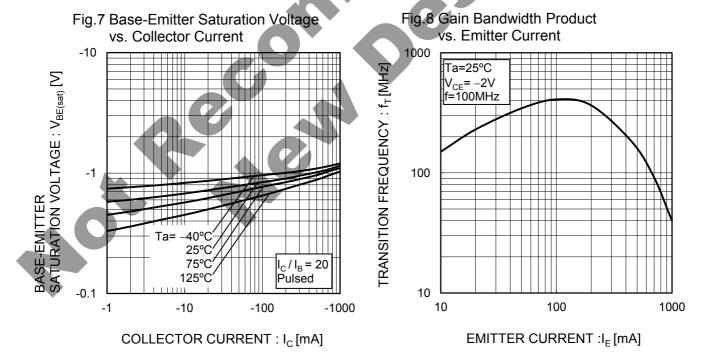


COLLECTOR CURRENT : I_C [mA]

●Electrical characteristic curves(Ta = 25°C)

COLLECTOR CURRENT : Ic [mA]

Fig.6 Collector-Emitter Saturation Voltage Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II) vs. Collector Current (I) -1 -10 $I_{\rm C} / I_{\rm B} = 20$ T_a=25°C COLLECTOR-EMITTER SATURATION VOLTAGE : V_{CE(sat)} [V] SATURATION VOLTAGE: V_{CE(sat)} [V] Pulsed Pulsed -1 COLLECTOR-EMITTER -0.1 -0.1 a=125°C 75°C 25°C -40°C -0.01 -100 -10 -100 -1000 -1000 -1

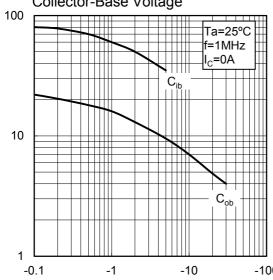


COLLECTOR CURRENT : I_C [mA]

COLLECTOR OUTPUT CAPACITANCE: Cob [pF] EMITTER INPUT CAPACITANCE: Cib [pF]

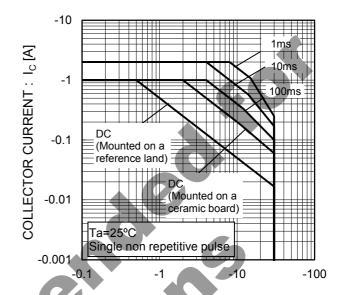
●Electrical characteristic curves(Ta = 25°C)

Fig.9 Emitter input capacitance vs.
Emitter-Base Voltage
Collector output capacitance vs.
Collector-Base Voltage



COLLECTOR - BASE VOLTAGE : V_{CB} [V] EMITTER - BASE VOLTAGE : V_{EB} [V]

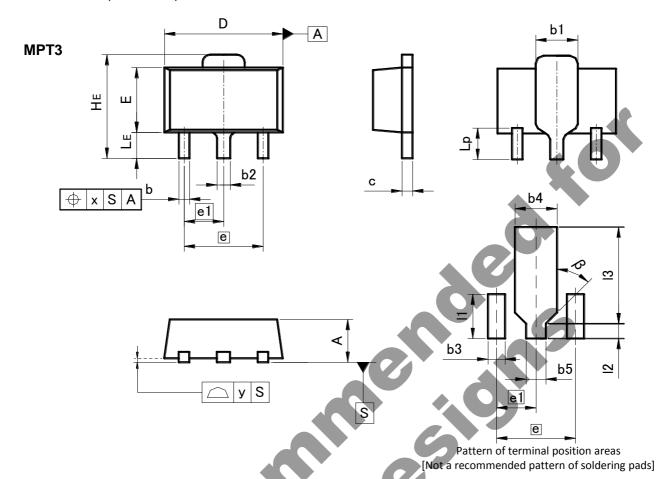
Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE : $V_{CE}\ [V]$



●Dimensions (Unit: mm)



DIM	MILIM	ETERS	INCHES		
DIIVI	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
C	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
E	2.40	2.70	0.094	0.106	
е	3.0	00	0.118		
e1	1.	50	0.0	159	
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
Х		0.15	_	0.006	
У	_	0.10	_	0.004	

DIM	MILIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
b3	-	0.65	-	0.026	
b4	-	1.70	-	0.067	
b5	1	0.75	1	0.030	
l1	-	1.71	1	0.067	
12	-	0.58	1	0.023	
13	_	3.72	_	0.146	
β	45°		45	0	

Dimension in mm / inches

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